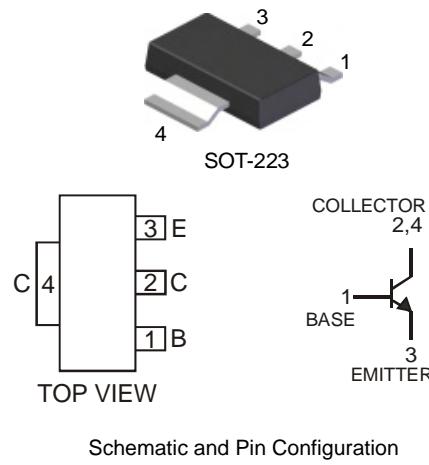


Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DZT2907A)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)



Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Continuous Current	I_C	600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 3)	P_d	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	°C

Notes:

- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Device mounted on FR-4 PCB pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	$V_{(\text{BR})\text{CBO}}$	75	—	V	$I_C = 10\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	40	—	V	$I_C = 10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(\text{BR})\text{EBO}}$	6	—	V	$I_E = 10\mu\text{A}, I_C = 0$
Collector Cut-Off Current	I_{CBO}	—	10	nA	$V_{\text{CB}} = 50\text{V}, I_E = 0$
		—	10	μA	$V_{\text{CB}} = 50\text{V}, I_E = 0, T_A = 150^\circ\text{C}$
Emitter Cut-Off Current	I_{EBO}	—	10	nA	$V_{\text{EB}} = 3\text{V}, I_C = 0$
Collector-Emitter Cut-Off Current	I_{CEX}	—	10	nA	$V_{\text{CE}} = 60\text{V}, V_{\text{EB}(\text{off})} = 3\text{V}$
ON CHARACTERISTICS (Note 4)					
Collector-Emitter Saturation Voltage	$V_{\text{CE}(\text{SAT})}$	—	0.3	V	$I_C = 150\text{mA}, I_B = 15\text{mA}$
		—	1.0	V	$I_C = 500\text{mA}, I_B = 50\text{mA}$
Base-Emitter Saturation Voltage	$V_{\text{BE}(\text{SAT})}$	0.6	1.2	V	$I_C = 150\text{mA}, I_B = 15\text{mA}$
		—	2.0	V	$I_C = 500\text{mA}, I_B = 50\text{mA}$
DC Current Gain	h_{FE}	35	—	V	$I_C = 0.1\text{mA}, V_{\text{CE}} = 10\text{V}$
		50	—		$I_C = 1\text{mA}, V_{\text{CE}} = 10\text{V}$
		75	—		$I_C = 10\text{mA}, V_{\text{CE}} = 10\text{V}$
		35	—		$I_C = 10\text{mA}, V_{\text{CE}} = 10\text{V}, T_A = -55^\circ\text{C}$
		100	300		$I_C = 150\text{mA}, V_{\text{CE}} = 10\text{V}$
		50	—		$I_C = 150\text{mA}, V_{\text{CE}} = 1\text{V}$
		40	—		$I_C = 500\text{mA}, V_{\text{CE}} = 10\text{V}$
SMALL SIGNAL CHARACTERISTICS					
Transition Frequency	f_T	300	—	MHz	$I_C = 20\text{mA}, V_{\text{CE}} = 20\text{V}, f = 100\text{MHz}$
Output Capacitance	C_{obo}	—	8	pF	$V_{\text{CB}} = 10\text{V}, I_E = 0, f = 1\text{MHz}$
Input Capacitance	C_{ibo}	—	25	pF	$V_{\text{EB}} = 0.5\text{V}, I_C = 0, f = 1\text{MHz}$
SWITCHING CHARACTERISTICS					
Delay Time	t_d	—	10	ns	$V_{\text{CE}} = 30\text{V}, V_{\text{EB}(\text{off})} = 0.5\text{V}, I_C = 150\text{mA}, I_B1 = 15\text{mA}$
Rise Time	t_r	—	25	ns	
Storage Time	t_s	—	225	ns	
Fall Time	t_f	—	60	ns	

Notes: 4. Measured under pulsed conditions. Pulse width = 300 μs . Duty Cycle, $d \leq 2\%$.

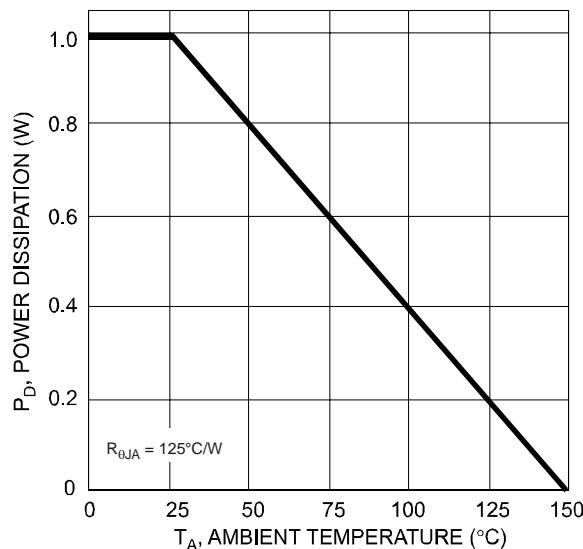


Fig. 1 Power Dissipation vs. Ambient Temperature

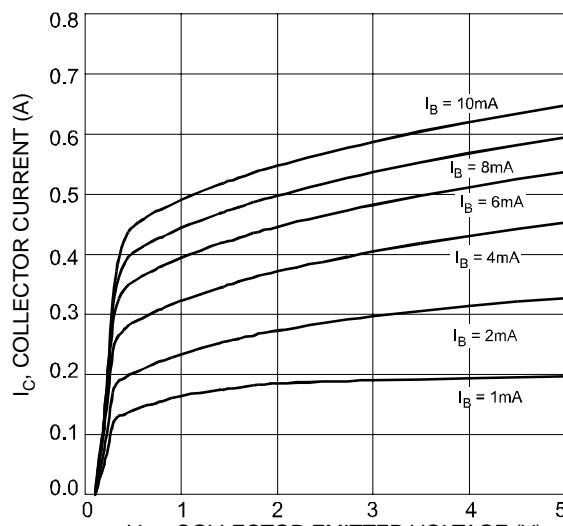


Fig. 2 Typical Collector Current vs. Collector Emitter Voltage

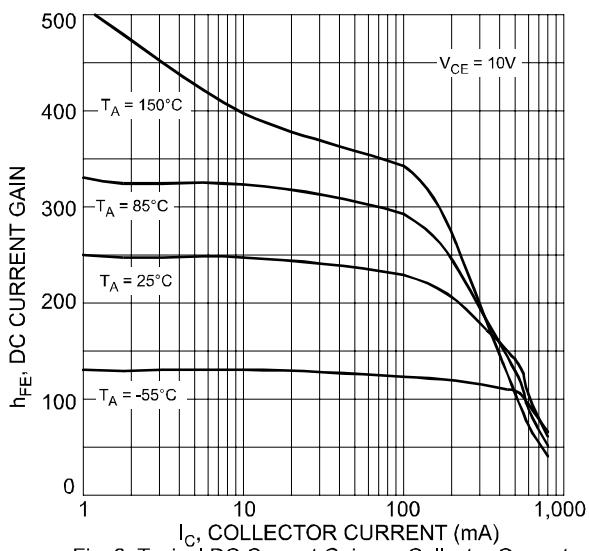


Fig. 3 Typical DC Current Gain vs. Collector Current

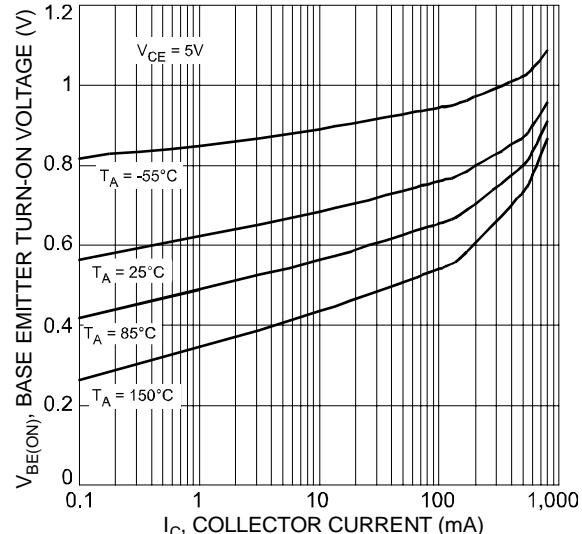


Fig. 5 Typical Base Emitter Turn-On Voltage vs. Collector Current

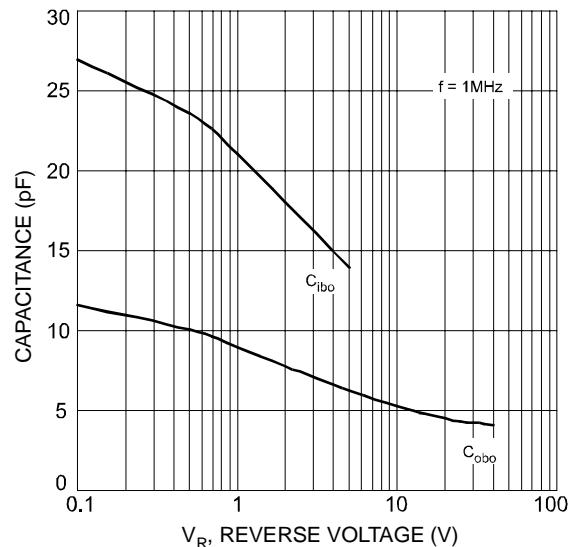


Fig. 7 Typical Capacitance Characteristics

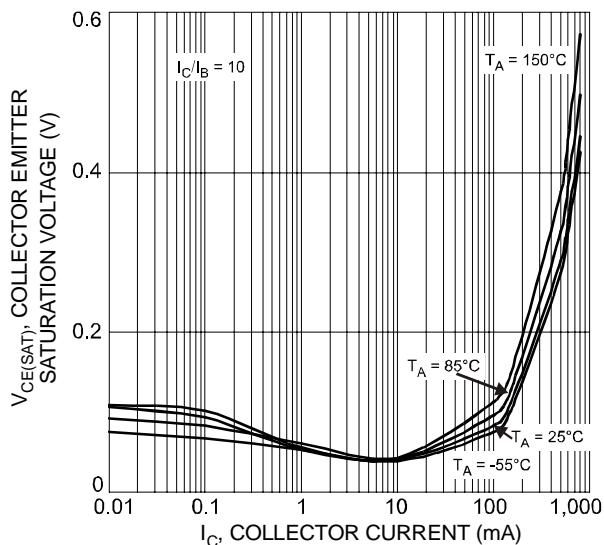


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

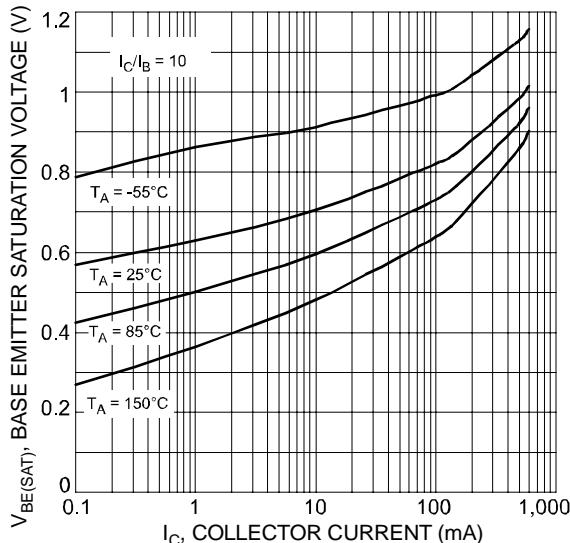


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current

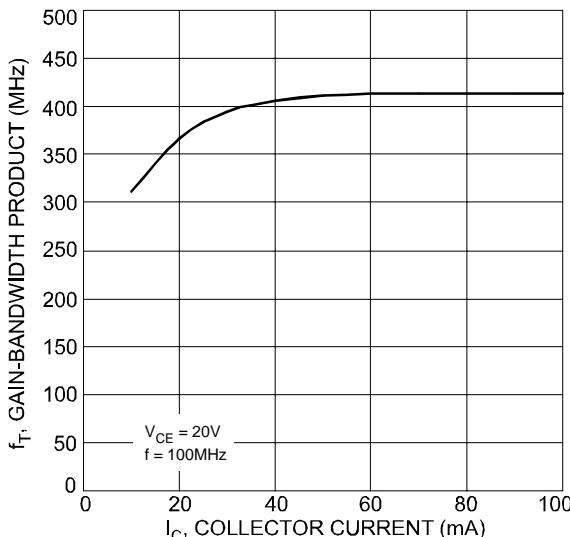


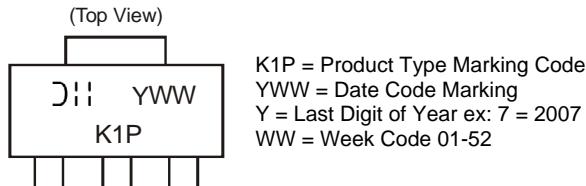
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 5)

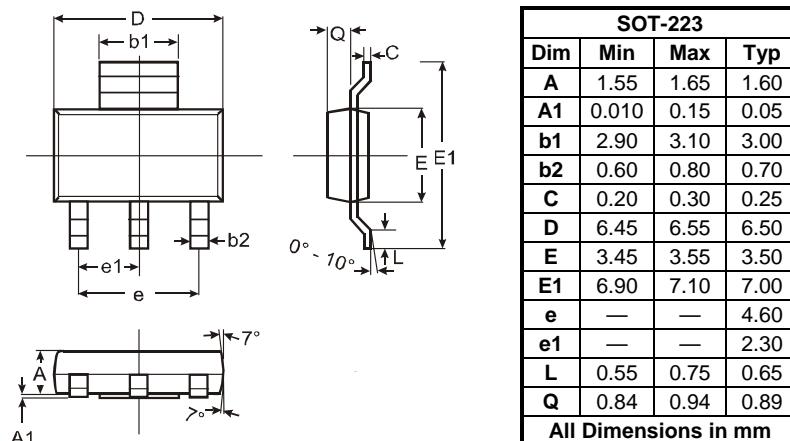
Device	Packaging	Shipping
DZT2222A-13	SOT-223	2500/Tape & Reel

Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

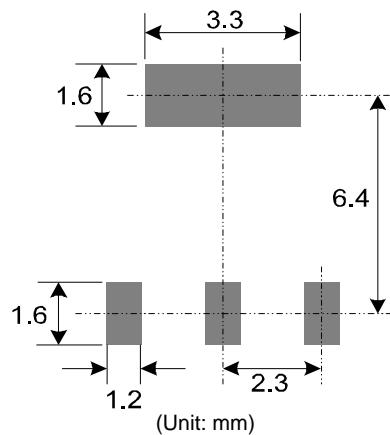
Marking Information



Package Outline Dimensions



Suggested Pad Layout: (Based on IPC-SM-782)



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